4-Bit D Type Latch

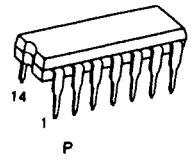
The TC74HC77A is a high speed CMOS 4-BIT D-TYPE LATCH fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

It contains two groups of 2-bit latches controlled by an enable input (G1,2 or G3,4) and these two group maybe used in different circuits.

The data applied to the data inputs are transferred to respective Q outputs when the enable input is held high. When the enable input is low, the outputs remain at the level at the time the enable goes low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.



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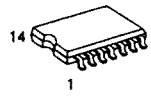

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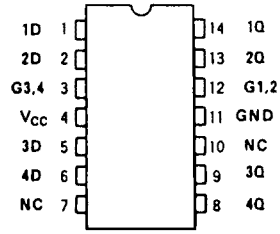
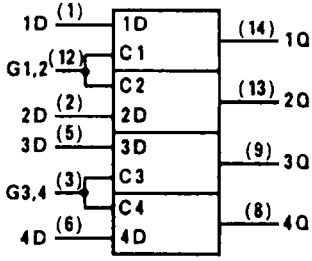
Features

- High Speed: t_{PD} = 10ns(Typ.) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 2μA(Max.) at Ta = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28%V_{CC}(Min.)
- Output Drive Capability: 10 LSTTL Loads
- Symmetrical Output Impedance: $|I_{OH}| = I_{OL}$ = 4mA(Min.)
- Balanced Propagation Delays: $t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range: V_{CC}(opr) = 2V ~ 6V
- Pin and Function Compatible with 74LS77



(TOP VIEW)
NC:NO CONNECTION

Pin Assignment



IEC Logic Symbol

Truth Table

Inputs		Outputs	Function
D	G	Q	
L	H	L	–
H	H	H	–
X	L	Q_n	Latch

X: Don't Care

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage Range	V_{CC}	-0.5 ~ 7	V
DC Input Voltage	V_{IN}	-0.5 ~ V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	-0.5 ~ V_{CC} + 0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	500(DIP)*/180(MFP)	mW
Storage Temperature	T_{stg}	-65 ~ 150	°C
Lead Temperature 10sec	T_L	300	°C

*500mW in the range of Ta = -40°C ~ 65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C shall be applied until 300mW.

Recommended Operating Conditions

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	2 ~ 6	V
Input Voltage	V_{IN}	0 ~ V_{CC}	V
Output Voltage	V_{OUT}	0 ~ V_{CC}	V
Operating Temperature	T_{opr}	-40 ~ 85	°C
Input Rise and Fall Time	t_r, t_f	0 ~ 1000(V_{CC} = 2.0V) 0 ~ 500(V_{CC} = 4.5V) 0 ~ 400(V_{CC} = 6.0V)	ns

DC Electrical Characteristics

Parameter	Symbol	Test Condition		Ta = 25°C				Ta = -40 ~ 85°C		Unit
				V_{CC}	Min	Typ.	Max.	Min.	Max.	
High-Level Input Voltage	V_{IH}	–		2.0 4.5 6.0	1.5 3.15 4.2	– – –	– – –	1.5 3.15 4.2	– – –	V
Low-Level Input Voltage	V_{IL}	–		2.0 4.5 6.0	– – –	– – –	0.5 1.35 1.8	– – –	0.5 1.35 1.8	V
High-Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -20μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	– – –	1.9 4.4 5.9	– – –	V
			I_{OH} = -4 mA I_{OH} = -5.2mA	4.5 6.0	4.18 5.68	4.31 5.80	– –	4.13 5.63	– –	
Low-Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20μA	2.0 4.5 6.0	– – –	0.0 0.0 0.0	0.1 0.1 0.1	– – –	0.1 0.1 0.1	V
			I_{OL} = 4 mA I_{OL} = 5.2mA	4.5 6.0	– –	0.17 0.18	0.26 0.26	– –	0.33 0.33	
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	–	–	±0.1	–	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	–	–	2.0	–	20.0	

Timing Requirements (Input $t_r = t_f = 6ns$)

Parameter	Symbol	Test Condition		Ta = 25°C		Ta = -40 ~ 85°C	Unit
			V_{CC}	Typ.	Limit	Limit	
Minimum Pulse Width (G)	$t_{W(H)}$	–	2.0	–	75	95	ns
			4.5	–	15	19	
			6.0	–	13	16	
Minimum Set-up Time	t_s	–	2.0	–	50	65	
			4.5	–	10	13	
			6.0	–	9	11	
Minimum Hold Time	t_h	–	2.0	–	25	30	
			4.5	–	5	6	
			6.0	–	4	5	

AC Electrical Characteristics ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C)

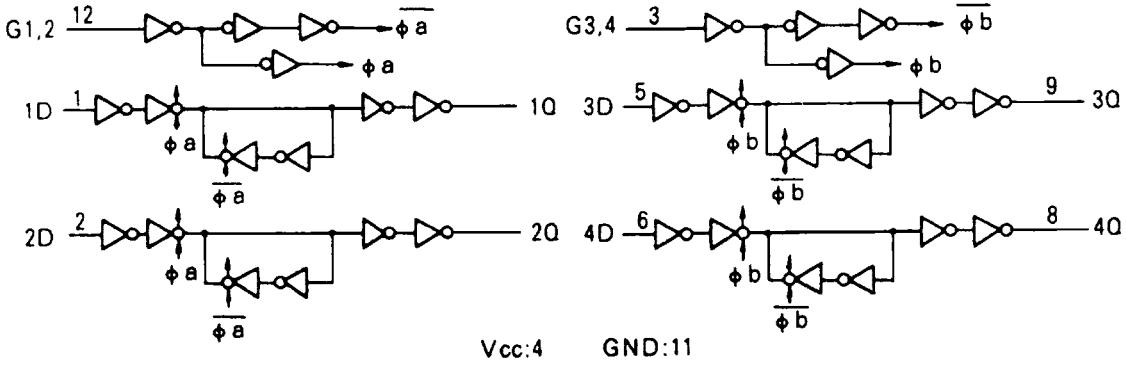
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output Transition Time	t_{TLH} t_{THL}	–	–	4	8	ns
Propagation Delay Time (DATA--Q)	t_{pLH} t_{pHL}	–	–	10	17	
Propagation Delay Time (G--Q)	t_{pLH} t_{pHL}	–	–	10	17	

AC Electrical Characteristics ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

Parameter	Symbol	Test Condition		Ta = 25°C			Ta = -40 ~ 85°C		Unit
			V_{CC}	Min	Typ.	Max.	Min.	Max.	
Output Transition Time	t_{TLH} t_{THL}	–	2.0	–	30	75	–	95	ns
			4.5	–	8	15	–	19	
			6.0	–	7	13	–	16	
Propagation Delay Time (DATA--Q)	t_{pLH} t_{pHL}	–	2.0	–	39	100	–	125	
			4.5	–	13	20	–	25	
			6.0	–	11	17	–	21	
Propagation Delay Time (G--Q)	t_{pLH} t_{pHL}	–	2.0	–	39	100	–	125	
			4.5	–	13	20	–	25	
			6.0	–	11	17	–	21	
Input Capacitance	C_{IN}	–		–	5	10	–	10	pF
Power Dissipation Capacitance	C_{PD}(1)	–		–	20	–	–	–	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$I_{CC(opr)} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}/4$(per Gate)



Logic Diagram